

D8

substrate is one of a sapphire substrate, spinel substrate, perovskite yttrium aluminate substrate [or] and SiC substrate.

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12. (Amended) The semiconductor device according to claim 9 wherein said semiconductor device is an FET using nitride III-V compound semiconductors.

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**Please add the following new Claim 24.**

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24. (New) A semiconductor device comprising:

a single-crystal substrate made of a material different from nitride III-V compound

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semiconductors, and

a device formed on one major surface of said single-crystal substrate by using III-V compound semiconductors,

wherein electrical connection to said device is made directly through a via hole formed in said single-crystal substrate;.

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